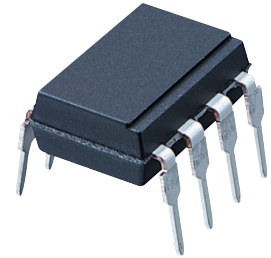


PC923L0NSZ Series

High Speed, Gate Drive DIP 8 pin
*OPIC Photocoupler



■ Description

PC923L0NSZ Series contains a LED optically coupled to an OPIC chip.

It is packaged in a 8 pin DIP, available in SMT gullwing lead form option.

Input-output isolation voltage(rms) is 5.0 kV, High speed response (t_{PHL} , t_{PLH} : MAX. 0.5 μ s).

■ Features

1. 8 pin DIP package
2. Double transfer mold package
(Ideal for Flow Soldering)
3. Built-in direct drive circuit for MOSFET / IGBT drive
(I_{O1P} , I_{O2P} : 0.6 A)
4. High speed response (t_{PHL} , t_{PLH} : MAX. 0.5 μ s)
5. Wide operating supply voltage range
(V_{CC} =15 to 30 V)
6. High noise immunity due to high instantaneous common mode rejection voltage (CM_H : MIN. -15kV/ μ s, CM_L : MIN. 15kV/ μ s)
7. High isolation voltage between input and output
($V_{iso(rms)}$: 5.0 kV)

■ Agency approvals/Compliance

1. Recognized by UL1577 (Double protection isolation), file No. E64380 (as model No. **PC923L**)
2. Approved by VDE (VDE0884) (as an option), file No. 87446 (as model No. **PC923L**)
3. Package resin : UL flammability grade (94V-0)

■ Applications

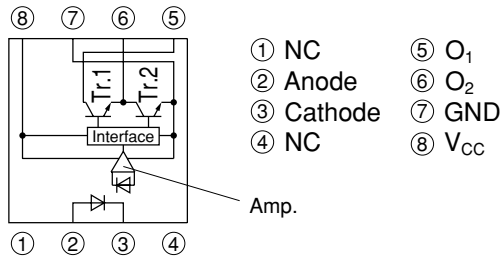
1. IGBT/MOSFET gate drive for inverter control

* "OPIC"(Optical IC) is a trademark of the SHARP Corporation. An OPIC consists of a light-detecting element and a signal-processing circuit integrated onto a single chip.

Notice The content of data sheet is subject to change without prior notice.

In the absence of confirmation by device specification sheets, SHARP takes no responsibility for any defects that may occur in equipment using any SHARP devices shown in catalogs, data books, etc. Contact SHARP in order to obtain the latest device specification sheets before using any SHARP device.

■ Internal Connection Diagram

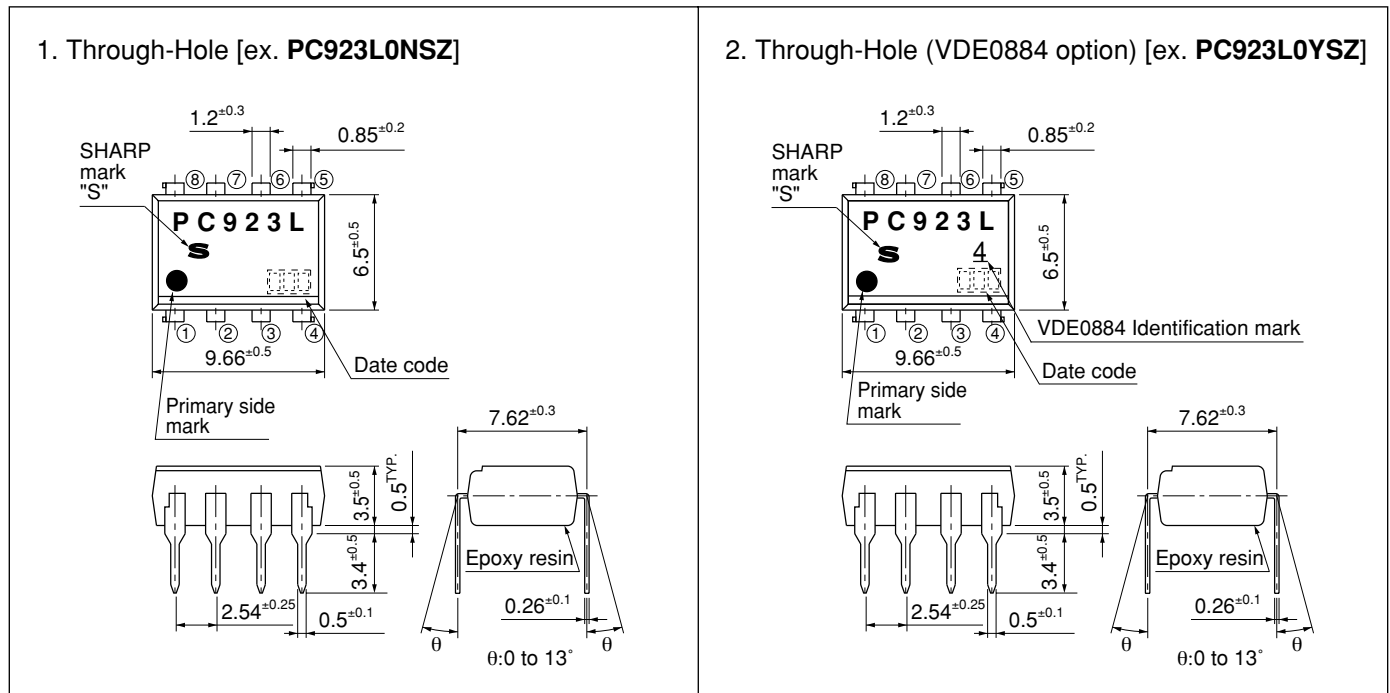


■ Truth table

| Input | O ₂ Terminal output | Tr. 1 | Tr. 2 |
|-------|--------------------------------|-------|-------|
| ON | High level | ON | OFF |
| OFF | Low level | OFF | ON |

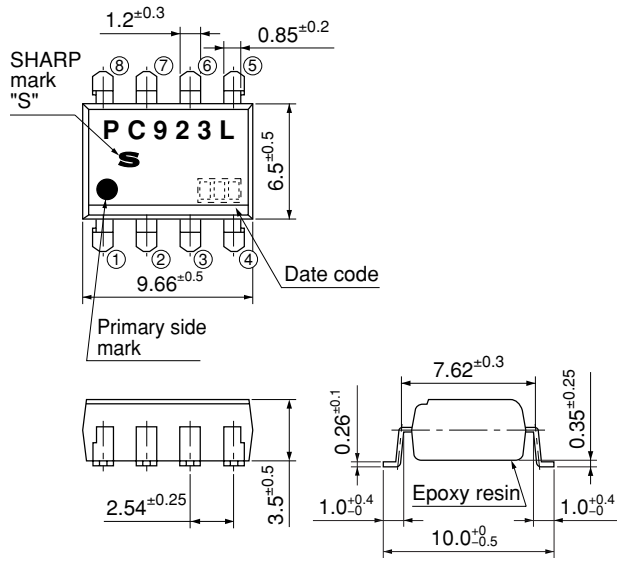
■ Outline Dimensions

(Unit : mm)

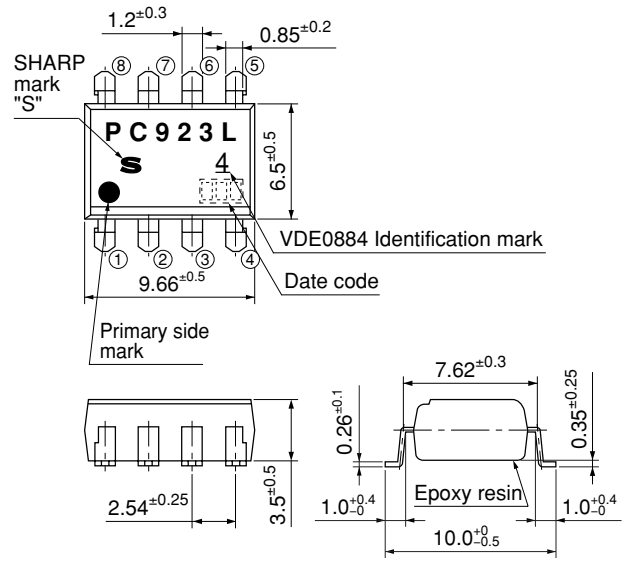


(Unit : mm)

3. SMT Gullwing Lead-Form [ex. **PC923L0NIP**]



4. SMT Gullwing Lead-Form (VDE0884 option)
[ex. **PC923L0YIP**]



Product mass : approx. 0.55g

Date code (3 digit)

| 1st digit | | | | 2nd digit | | 3rd digit | |
|--------------------|------|------|------|---------------------|------|--------------------|------|
| Year of production | | | | Month of production | | Week of production | |
| A.D. | Mark | A.D | Mark | Month | Mark | Week | Mark |
| 1990 | A | 2002 | P | January | 1 | 1st | 1 |
| 1991 | B | 2003 | R | February | 2 | 2nd | 2 |
| 1992 | C | 2004 | S | March | 3 | 3rd | 3 |
| 1993 | D | 2005 | T | April | 4 | 4th | 4 |
| 1994 | E | 2006 | U | May | 5 | 5.6th | 5 |
| 1995 | F | 2007 | V | June | 6 | | |
| 1996 | H | 2008 | W | July | 7 | | |
| 1997 | J | 2009 | X | August | 8 | | |
| 1998 | K | 2010 | A | September | 9 | | |
| 1999 | L | 2011 | B | October | O | | |
| 2000 | M | 2012 | C | November | N | | |
| 2001 | N | ∴ | ∴ | December | D | | |

repeats in a 20 year cycle

Country of origin
Japan

■ Absolute Maximum Ratings (T_a=25°C)

| Parameter | Symbol | Rating | Unit | |
|----------------------------|---------------------------------------|------------------|------|----|
| Input | *1 Forward current | I _F | 20 | mA |
| | Reverse voltage | V _R | 5 | V |
| Output | Supply voltage | V _{CC} | 35 | V |
| | O ₁ output current | I _{O1} | 0.1 | A |
| | *2 O ₁ Peak output current | I _{O1P} | 0.6 | A |
| | O ₂ output current | I _{O2} | 0.1 | A |
| | *2 O ₂ Peak output current | I _{O2P} | 0.6 | A |
| | O ₁ output voltage | V _{O1} | 35 | V |
| | *3 Power dissipation | P _O | 500 | mW |
| *4 Total power dissipation | P _{tot} | 550 | mW | |
| *5 Isolation voltage | V _{iso (rms)} | 5.0 | kV | |
| Operating temperature | T _{opr} | -40 to +85 | °C | |
| Storage temperature | T _{stg} | -55 to +125 | °C | |
| *6 Soldering temperature | T _{sol} | 270 | °C | |

*1 The derating factors of a absolute maximum ratings due to ambient temperature are shown in Fig.10

*2 Pulse width≤0.15μs, Duty ratio : 0.01

*3, 4 The derating factors of a absolute maximum ratings due to ambient temperature are shown in Fig.11

*5 AC for 1minute, 40 to 60 %RH, f=60Hz

*6 For 10s

■ Electro-optical Characteristics*7

(Unless otherwise specified T_a=T_{opr})

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit | |
|--------------------------|---|---|--|------------------|------|------|-------|
| Input | Forward voltage | V _{F1} | T _a =25°C, I _F =10mA | - | 1.6 | 1.75 | V |
| | | V _{F2} | T _a =25°C, I _F =0.2mA | 1.2 | 1.5 | - | V |
| | Reverse current | I _R | T _a =25°C, V _R =5V | - | - | 10 | μA |
| | Terminal capacitance | C _t | T _a =25°C, V=0, f=1MHz | - | 60 | 150 | pF |
| Output | Supply voltage | V _{CC} | - | 15 | - | 30 | V |
| | O ₁ Low level output voltage | V _{O1L} | V _{CC1} =12V, V _{CC2} =-12V, I _{O1} =0.1A, I _F =5mA | - | 0.2 | 0.4 | V |
| | O ₂ High level output voltage | V _{O2H} | V _{CC} =V _{O1} =24V, I _{O2} =-0.1A, I _F =5mA | 20 | 22 | - | V |
| | O ₂ Low level output voltage | V _{O2L} | V _{CC} =24V, I _{O2} =0.1A, I _F =0 | - | 0.5 | 0.8 | V |
| | O ₁ leak current | I _{O1L} | V _{CC} =V _{O1} =35V, I _F =0 | - | - | 500 | μA |
| | O ₂ leak current | I _{O2L} | V _{CC} =V _{O2} =35V, I _F =5mA | - | - | 500 | μA |
| | *9 High level supply current | I _{CCH} | V _{CC} =24V, I _F =5mA | - | 1.3 | 3.0 | mA |
| | *9 Low level supply current | I _{CCL} | V _{CC} =24V, I _F =0 | - | 1.3 | 3.0 | mA |
| | *8 "Low→High" input threshold current | I _{FLH} | T _a =25°C, V _{CC} =24V | 0.3 | 1.5 | 3.0 | mA |
| | | | V _{CC} =24V | 0.2 | - | 5.0 | mA |
| Isolation resistance | R _{ISO} | T _a =25°C, DC500V, 40 to 60%RH | 5×10 ¹⁰ | 10 ¹¹ | - | Ω | |
| Response time | "Low→High" propagation delay time | t _{PLH} | T _a =25°C, V _{CC} =24V, I _F =5mA R _G =47Ω, C _G =3 000pF | - | 0.3 | 0.5 | μs |
| | "High→Low" propagation delay time | t _{PHL} | | - | 0.3 | 0.5 | μs |
| | Rise time | t _r | | - | 0.2 | 0.5 | μs |
| | Fall time | t _f | | - | 0.2 | 0.5 | μs |
| Transfer characteristics | Instantaneous common mode rejection voltage (High level output) | CM _H | T _a =25°C, V _{CM} =1.5kV _(p-p) I _F =5mA, V _{CC} =24V, ΔV _{O2H} =2.0V | -15 | - | - | kV/μs |
| | Instantaneous common mode rejection voltage (Low level output) | CM _L | T _a =25°C, V _{CM} =1.5kV _(p-p) I _F =0, V _{CC} =24V, ΔV _{O2L} =2.0V | 15 | - | - | kV/μs |

*7 It shall connect a by-pass capacitor of 0.01μF or more between V_{CC} (pin ⑧) and GND (pin ⑦) near the device, when it measures the transfer characteristics and the output side characteristics

*8 I_{FLH} represents forward current when output goes from "Low" to "High" *9 O₂ output terminal is set open

■ Model Line-up

| Lead Form | Through-Hole | | SMT Gullwing | | | |
|-----------|-------------------|-------------------|-------------------|-------------------|-------------------|-------------------|
| Package | Sleeve | | | | Taping | |
| | 50pcs/sleeve | | | | 1 000pcs/reel | |
| VDE0884 | ——— | Approved | ——— | Approved | ——— | Approved |
| Model No. | PC923L0NSZ | PC923L0YSZ | PC923L0NIZ | PC923L0YIZ | PC923L0NIP | PC923L0YIP |

Please contact a local SHARP sales representative to inquire about production status and Lead-Free options.

Fig.1 Test Circuit for O₁ Low Level Output Voltage

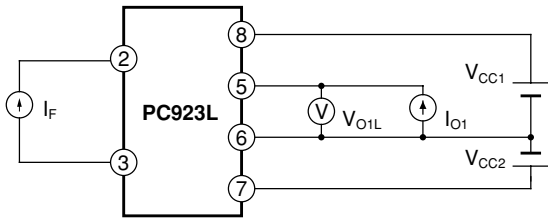


Fig.2 Test Circuit for O₂ High Level Output Voltage

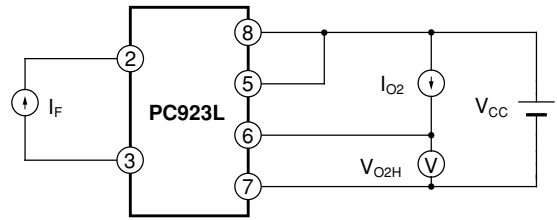


Fig.3 Test Circuit for O₂ Low Level Output Voltage

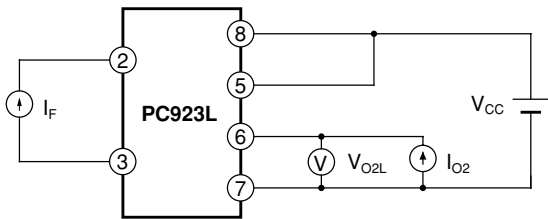


Fig.4 Test Circuit for O₁ Leak Current

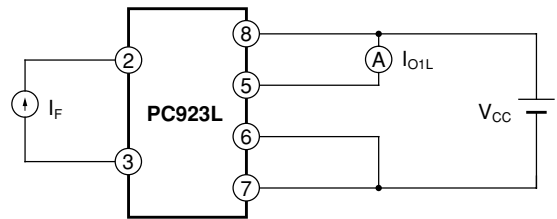


Fig.5 Test Circuit for O₂ Leak Current

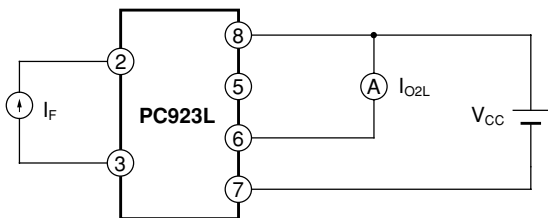


Fig.6 Test Circuit for High Level / Low Level Supply Current

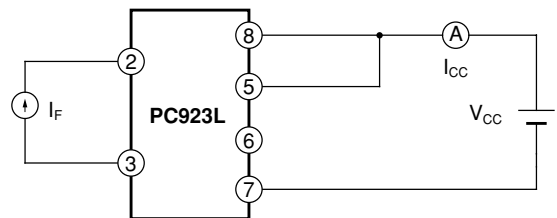


Fig.7 Test Circuit for "Low→High" Input Threshold Current

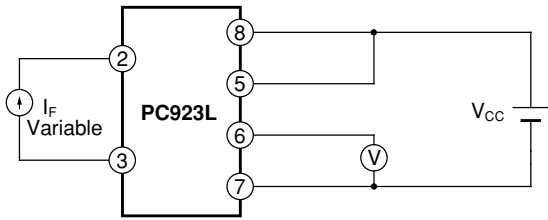


Fig.8 Test Circuit for Response Time

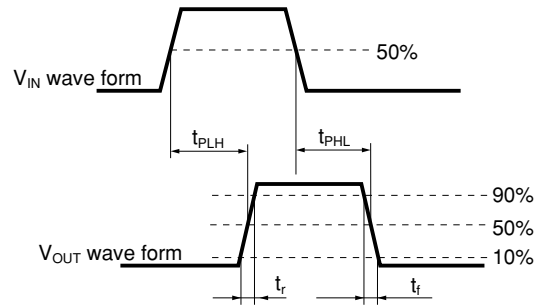
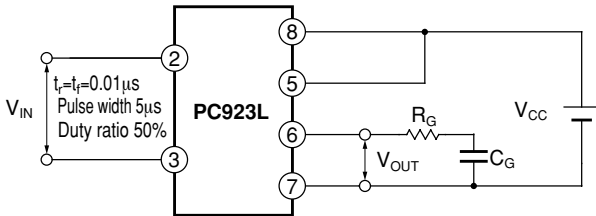


Fig.9 Test Circuit for Instantaneous Common Mode Rejection Voltage

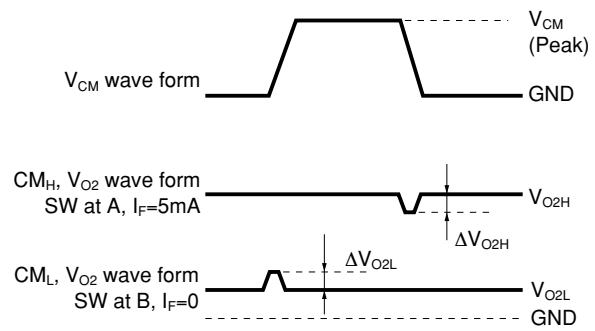
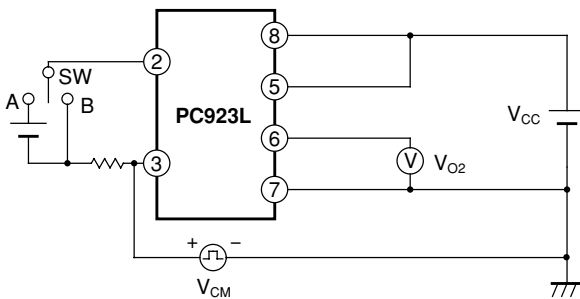


Fig.10 Forward Current vs. Ambient Temperature

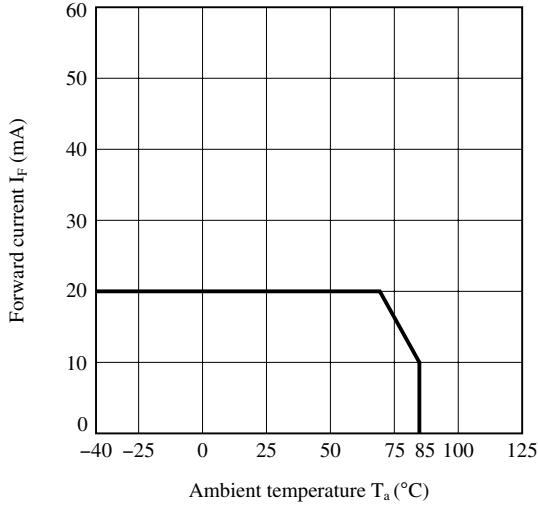


Fig.11 Power Dissipation vs. Ambient Temperature

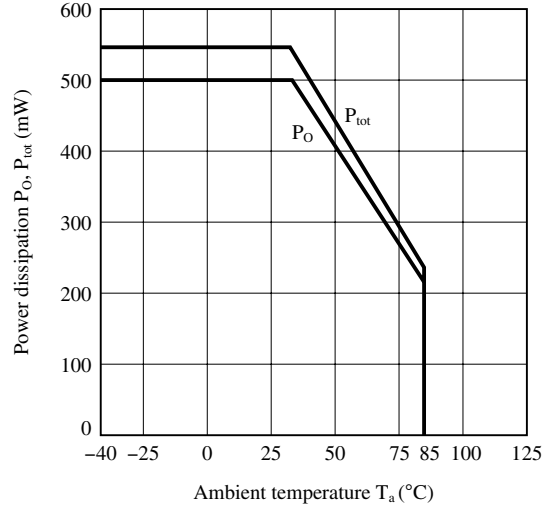


Fig.12 Forward Current vs. Forward Voltage

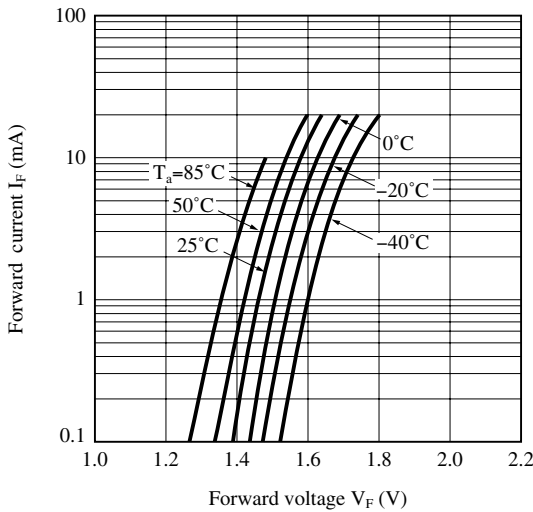


Fig.13 "Low→High" Relative Input Threshold Current vs. Supply Voltage

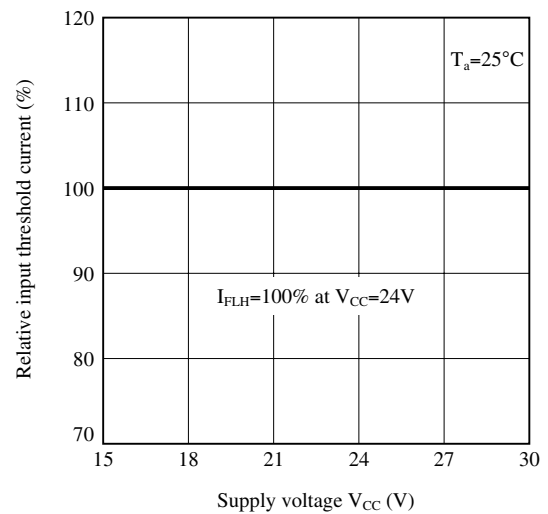


Fig.14 "Low→High" Relative Input Threshold Current vs. Ambient Temperature

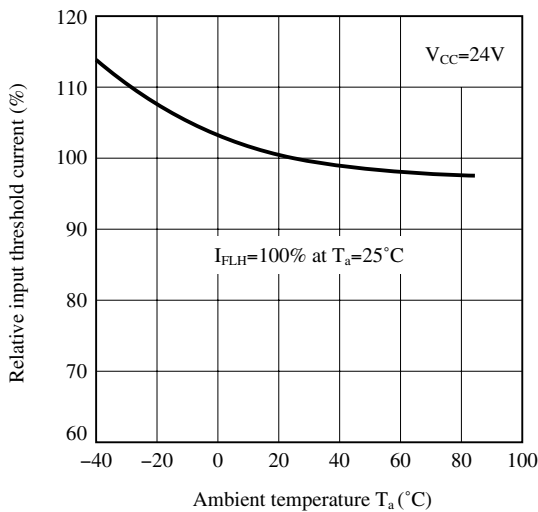


Fig.15 O₁ Low Level Output Voltage vs. O₁ Output Current

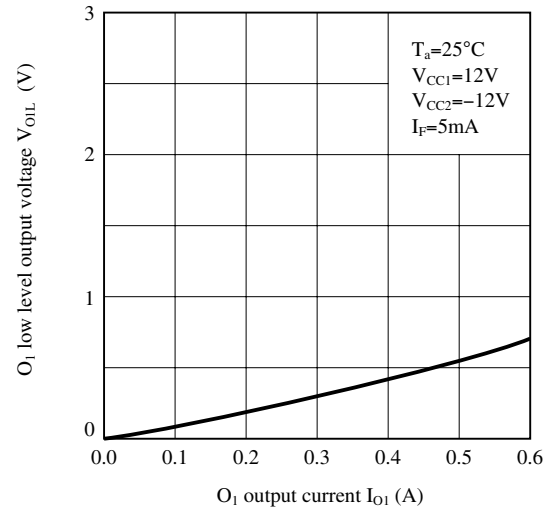


Fig.16 O₁ Low Level Output Voltage vs. Ambient Temperature

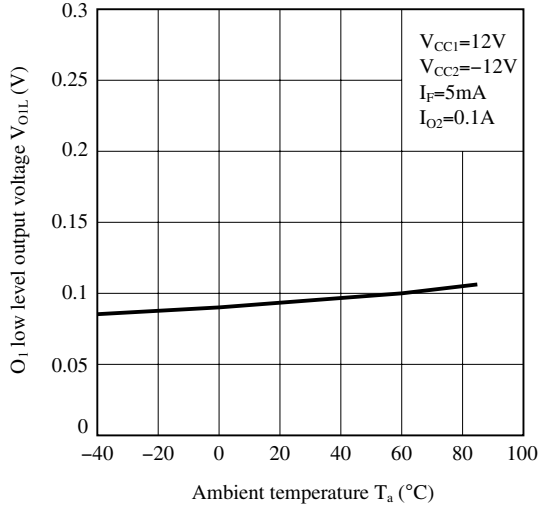


Fig.17 O₂ Output Voltage Drop vs. O₂ Output Current

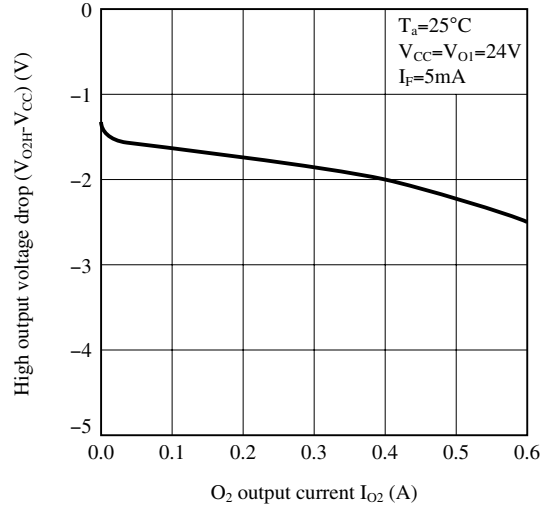


Fig.18 O₂ High Level Output Voltage vs. Supply Voltage

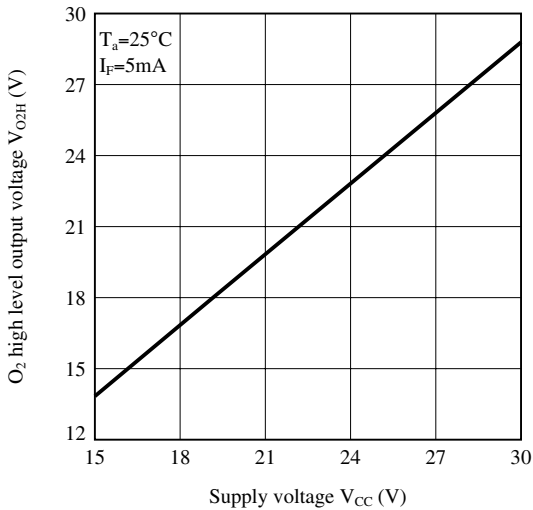


Fig.19 O₂ High Level Output Voltage vs. Ambient Temperature

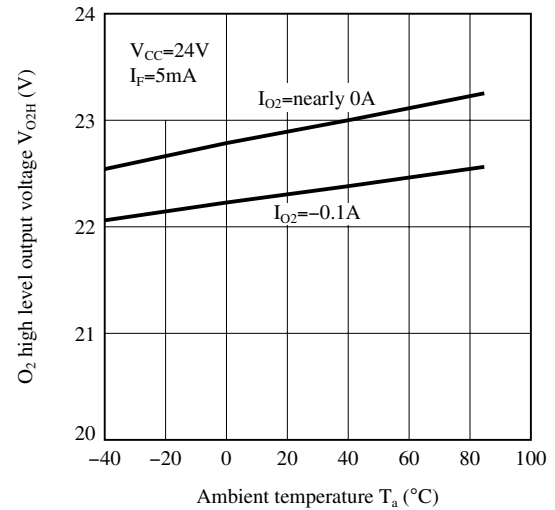


Fig.20 O₂ Low Level Output Voltage vs. O₂ Output Current

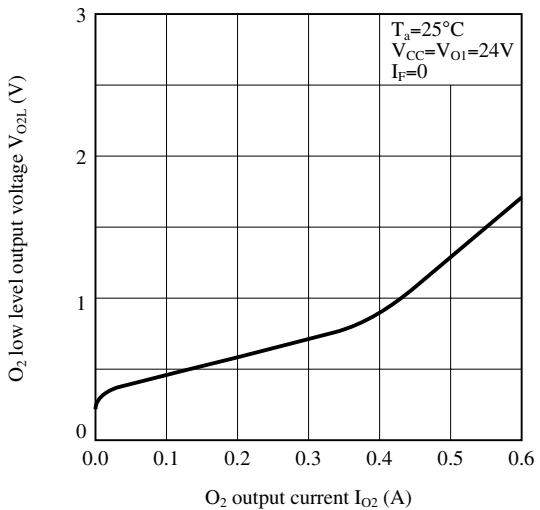


Fig.21 O₂ Low Level Output Voltage vs. Ambient Temperature

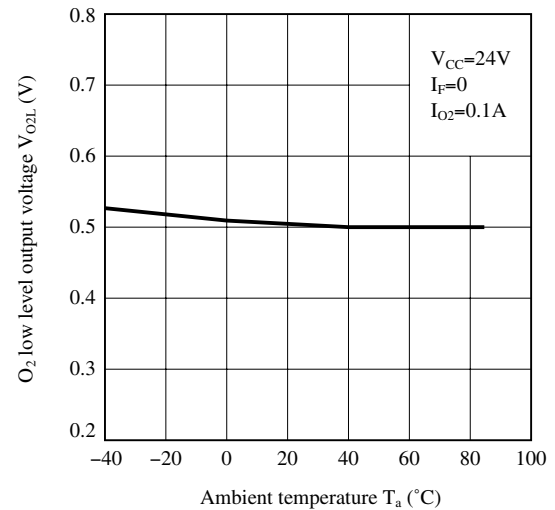


Fig.22 High Level Supply Current vs. Supply Voltage

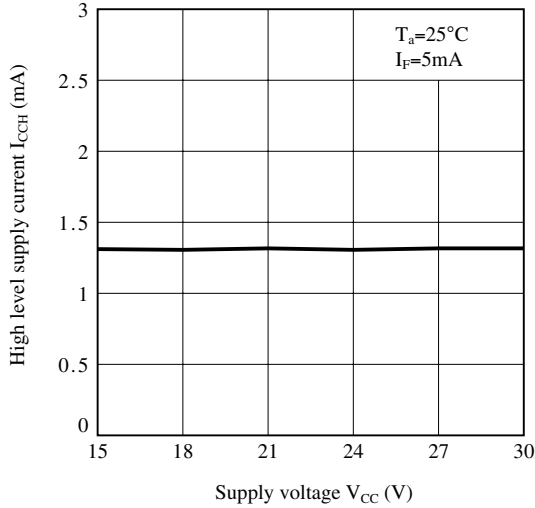


Fig.23 Low Level Supply Current vs. Supply Voltage

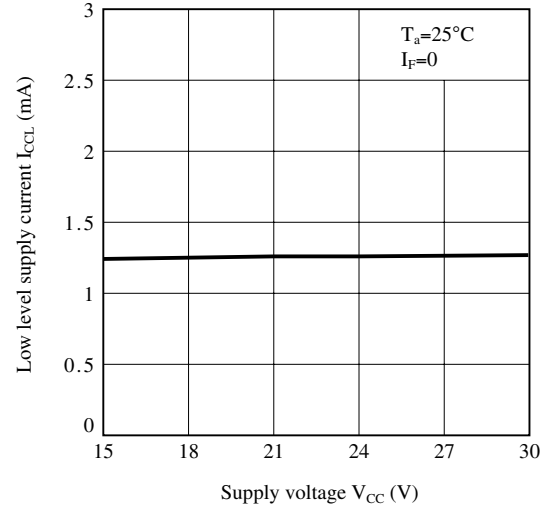


Fig.24 High Level Supply Current vs. Ambient Temperature

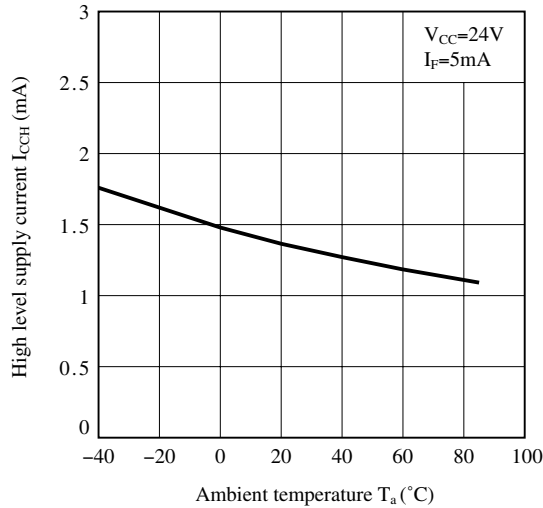


Fig.25 Low Level Supply Current vs. Ambient Temperature

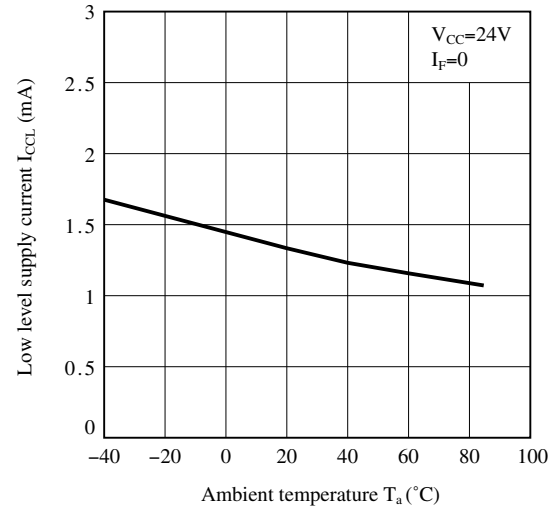


Fig.26 Propagation Delay Time vs. Forward Current

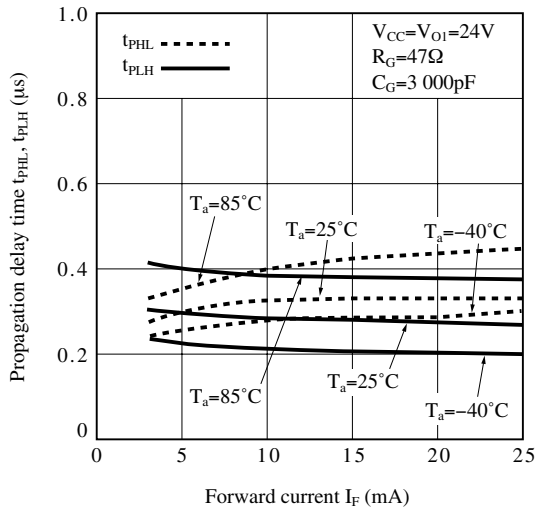
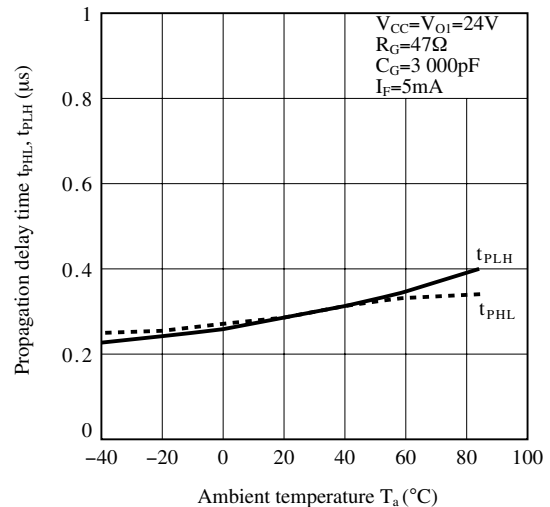


Fig.27 Propagation Delay Time vs. Ambient Temperature



Remarks : Please be aware that all data in the graph are just for reference and not for guarantee.

■ **Design Considerations**

● **Recommended operating conditions**

| Parameter | Symbol | MIN. | TYP. | MAX. | Unit |
|-----------------------|-----------|------|------|------|------|
| Forward current | I_F | 10 | – | 20 | mA |
| Supply voltage | V_{CC} | 15 | – | 30 | V |
| Operating temperature | T_{opr} | –40 | – | 70 | °C |

● **Notes about static electricity**

Transistor of detector side in bipolar configuration may be damaged by static electricity due to its minute design.

When handling these devices, general countermeasure against static electricity should be taken to avoid breakdown of devices or degradation of characteristics.

● **Design guide**

In order to stabilize power supply line, we should certainly recommend to connect a by-pass capacitor of 0.01 μ F or more between V_{CC} and GND near the device.

In case that some sudden big noise caused by voltage variation is provided between primary and secondary terminals of photocoupler some current caused by it is floating capacitance may be generated and result in false operation since current may go through LED or current may change.

If the photocoupler may be used under the circumstances where noise will be generated we recommend to use the bypass capacitors at the both ends of LED.

The detector which is used in this device, has parasitic diode between each pins and GND.

There are cases that miss operation or destruction possibly may be occurred if electric potential of any pin becomes below GND level even for instant.

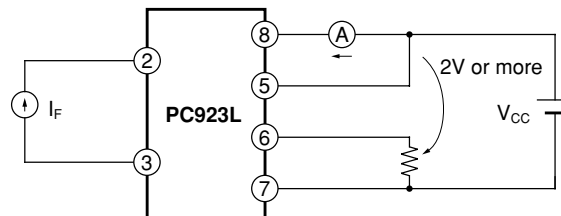
Therefore it shall be recommended to design the circuit that electric potential of any pin does not become below GND level.

This product is not designed against irradiation and incorporates non-coherent LED.

This photocoupler is dedicated to the use for IGBT or MOSFET Gate Drive.

Please do not use this for the other application.

As mentioned below, when the input is on, if DC load (resistor etc.) is connected between O_2 output pin 6 and GND pin 7 and if the electric potential V_{O2} goes approx. 2V below than electric potential V_{CC} pin 8 continuously, supply current I_{CC} may flow more than usually and go beyond power dissipation.

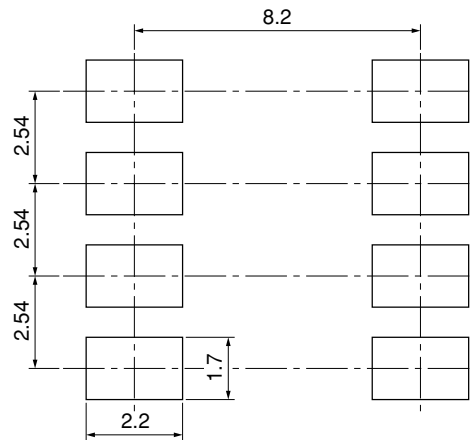


● Degradation

In general, the emission of the LED used in photocouplers will degrade over time.

In the case of long term operation, please take the general LED degradation (50% degradation over 5years) into the design consideration.

Please decide the input current which become 2times of MAX. I_{FLH} .

● Recommended Foot Print (reference)

(Unit : mm)

☆ For additional design assistance, please review our corresponding Optoelectronic Application Notes.

■ Manufacturing Guidelines

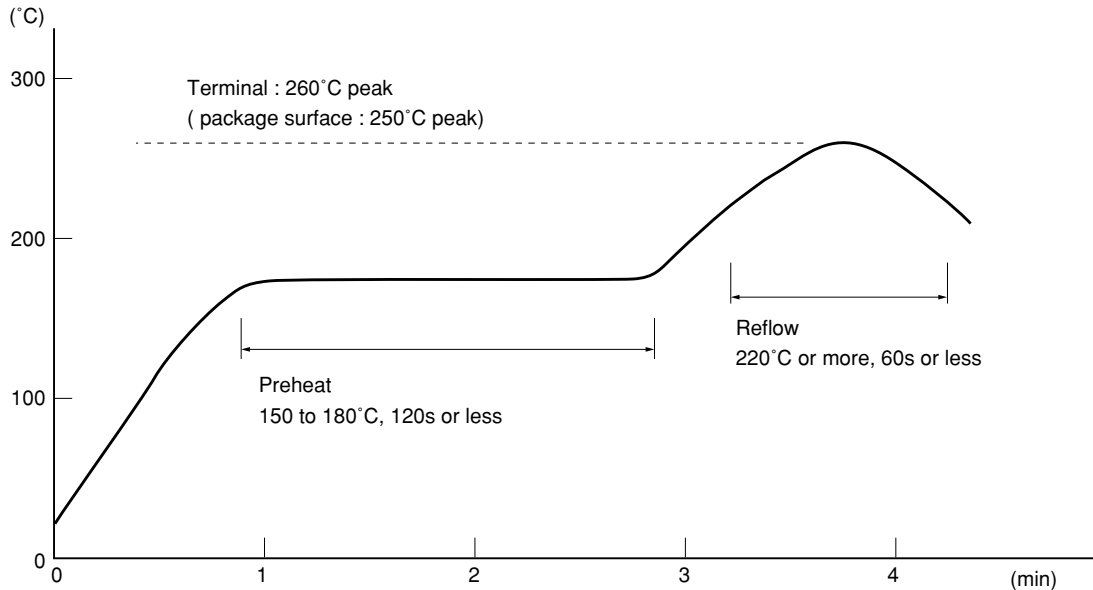
● Soldering Method

Reflow Soldering:

Reflow soldering should follow the temperature profile shown below.

Soldering should not exceed the curve of temperature profile and time.

Please don't solder more than twice.



Flow Soldering :

Due to SHARP's double transfer mold construction submersion in flow solder bath is allowed under the below listed guidelines.

Flow soldering should be completed below 270°C and within 10s.

Preheating is within the bounds of 100 to 150°C and 30 to 80s.

Please don't solder more than twice.

Hand soldering

Hand soldering should be completed within 3s when the point of solder iron is below 400°C.

Please don't solder more than twice.

Other notices

Please test the soldering method in actual condition and make sure the soldering works fine, since the impact on the junction between the device and PCB varies depending on the tooling and soldering conditions.

● Cleaning instructions**Solvent cleaning:**

Solvent temperature should be 45°C or below Immersion time should be 3minutes or less

Ultrasonic cleaning:

The impact on the device varies depending on the size of the cleaning bath, ultrasonic output, cleaning time, size of PCB and mounting method of the device.

Therefore, please make sure the device withstands the ultrasonic cleaning in actual conditions in advance of mass production.

Recommended solvent materials:

Ethyl alcohol, Methyl alcohol and Isopropyl alcohol

In case the other type of solvent materials are intended to be used, please make sure they work fine in actual using conditions since some materials may erode the packaging resin.

● Presence of ODC

This product shall not contain the following materials.

And they are not used in the production process for this device.

Regulation substances : CFCs, Halon, Carbon tetrachloride, 1.1.1-Trichloroethane (Methylchloroform)

Specific brominated flame retardants such as the PBBOs and PBBs are not used in this product at all.

■ Package specification**● Sleeve package**

Package materials

Sleeve : HIPS (with anti-static material)

Stopper : Styrene-Elastomer

Package method

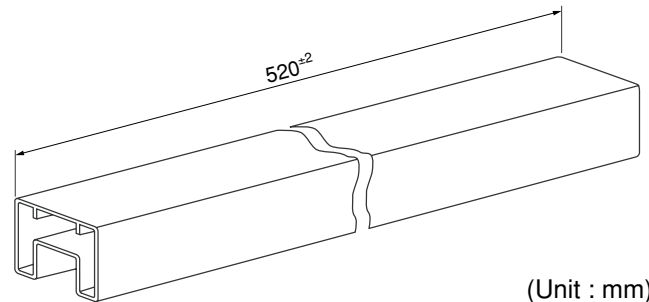
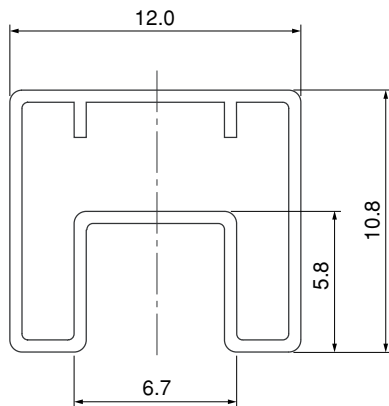
MAX. 50 pcs. of products shall be packaged in a sleeve.

Both ends shall be closed by tabbed and tabless stoppers.

The product shall be arranged in the sleeve with its primary side mark on the tabless stopper side.

MAX. 20 sleeves in one case.

Sleeve outline dimensions



(Unit : mm)

● **Tape and Reel package**

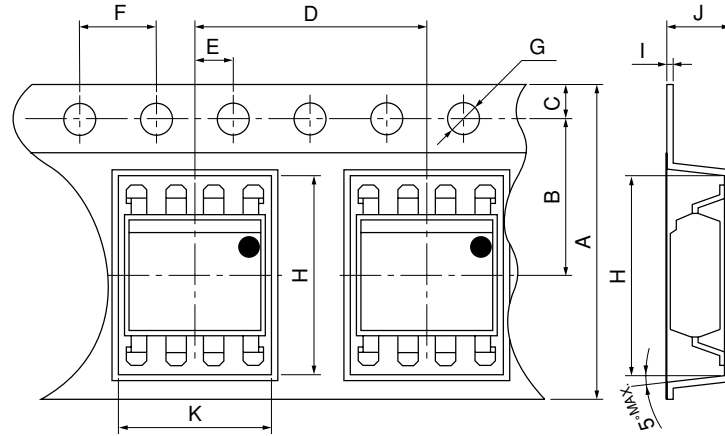
Package materials

Carrier tape : A-PET (with anti-static material)

Cover tape : PET (three layer system)

Reel : PS

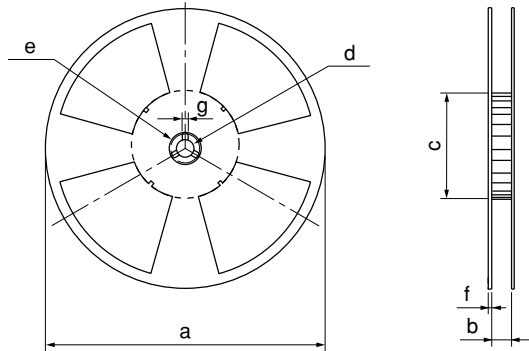
Carrier tape structure and Dimensions



Dimensions List (Unit : mm)

| A | B | C | D | E | F | G |
|----------|----------|----------|----------|---------|---------|----------|
| 16.0±0.3 | 7.5±0.1 | 1.75±0.1 | 12.0±0.1 | 2.0±0.1 | 4.0±0.1 | φ1.5±0.1 |
| H | I | J | K | | | |
| 10.4±0.1 | 0.4±0.05 | 4.2±0.1 | 10.2±0.1 | | | |

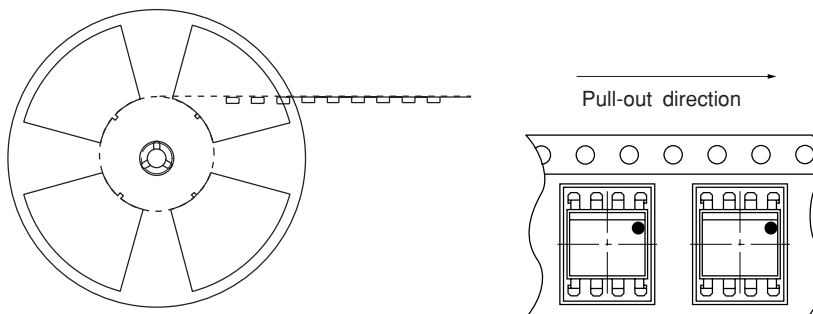
Reel structure and Dimensions



Dimensions List (Unit : mm)

| a | b | c | d |
|--------|----------|---------|--------|
| 330 | 17.5±1.5 | 100±1.0 | 13±0.5 |
| e | f | g | |
| 23±1.0 | 2.0±0.5 | 2.0±0.5 | |

Direction of product insertion



[Packing : 1 000pcs/reel]

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- Telecommunication equipment [terminal]
- Test and measurement equipment
- Industrial control
- Audio visual equipment
- Consumer electronics

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- Gas leakage sensor breakers
- Alarm equipment
- Various safety devices, etc.

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